

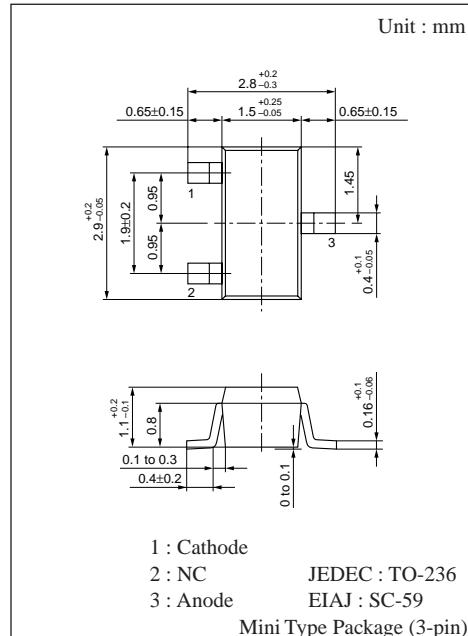
# MA200A

Silicon epitaxial planer type

For switching circuits

## ■ Features

- Small reverse current  $I_R$ , with extremely small leakage current
- $t_{rr}$  of a soft recovery type



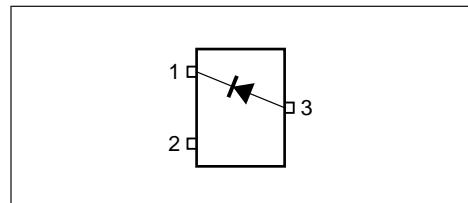
## ■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	$V_R$	80	V
Peak reverse voltage	$V_{RRM}$	80	V
Forward current (DC)	$I_F(AV)$	100	mA
Peak forward current	$I_{FRM}$	225	mA
Non-repetitive peak forward surge current	$I_{FSM}^*$	500	mA
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

\* t=1s

Marking Symbol : M4L

## ■ Internal Connection



## ■ Electrical Characteristics (Ta= 25°C)

Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	$I_{R1}$	$V_R= 75V$			10	nA
	$I_{R2}$	$V_R= 5V, Ta= 85^\circ C$			20	nA
Forward voltage (DC)	$V_F$	$I_F=100mA$			1.2	V
Reverse voltage (DC)	$V_R$	$I_R=100\mu A$	80			V
Terminal capacitance	$C_t$	$V_R= 0V, f=1MHz$			2.5	pF
Reverse recovery time	$t_{rr}^*$	$I_F=10mA, V_R= 6V$ $I_{rr}= 0.1 \cdot I_R, R_L=100\Omega$			100	ns

Note 1 : Rated input/output frequency : 100MHz

2 : \*  $t_{rr}$  measuring circuit

## ■ Marking

